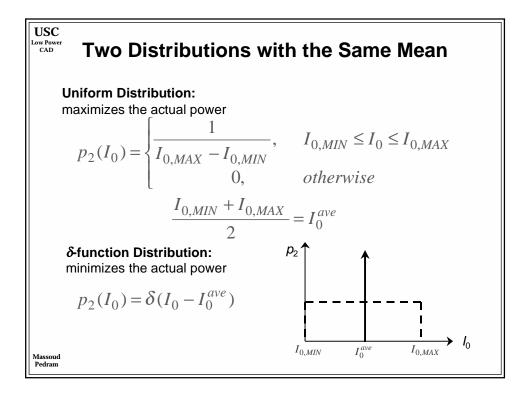
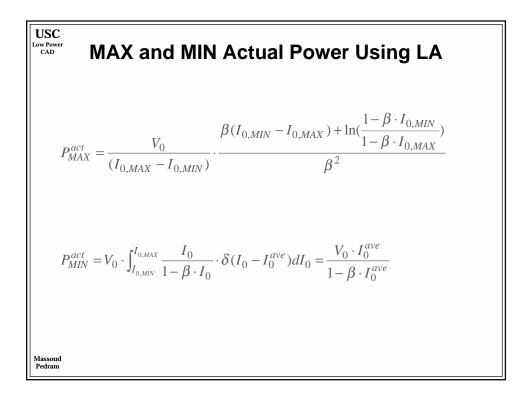


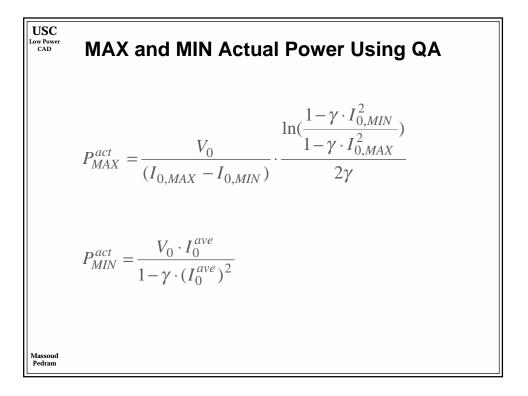
USC Law Power CAD The Actual Power Dissipation  $p_1$ : The profile (probability density function) of  $l_{dd}$   $p_2$ : The profile (probability density function) of  $l_0$   $p_1$  and  $p_2$  have the same form, but different scale Ideal power extracted from the battery:  $P^{ide} = \int_{I_{0,MIN}}^{I_{0,MAX}} V_0 \cdot I_0 \cdot p_2(I_0) dI_0$   $= V_0 \cdot \int_{I_{0,MIN}}^{I_{0,MAX}} I_0 \cdot p_2(I_0) dI_0 = V_0 \cdot I_0^{ave}$  Actual power extracted from the battery:  $P^{act} = V_0 \cdot \int_{I_{0,MIN}}^{I_{0,MAX}} \frac{I_0}{\mu(I_0)} \cdot p_2(I_0) dI_0$ 

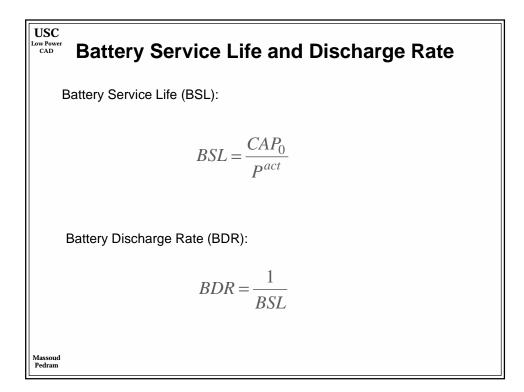
USC Low Power CAD
Actual Power Using LA and QA
Linear Approximation (LA):  $P^{act} = V_0 \cdot \int_{I_{0,MIN}}^{I_{0,MAX}} \frac{I_0}{1 - \beta \cdot I_0} \cdot p_2(I_0) dI_0$ Quadratic Approximation (QA):  $P^{act} = V_0 \cdot \int_{I_{0,MIN}}^{I_{0,MAX}} \frac{I_0}{1 - \gamma \cdot I_0^2} \cdot p_2(I_0) dI_0$ 

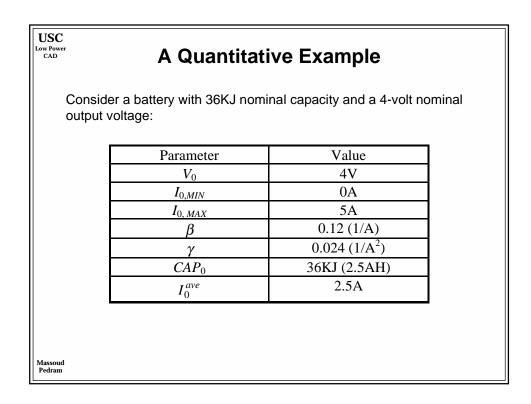
Massoud Pedram

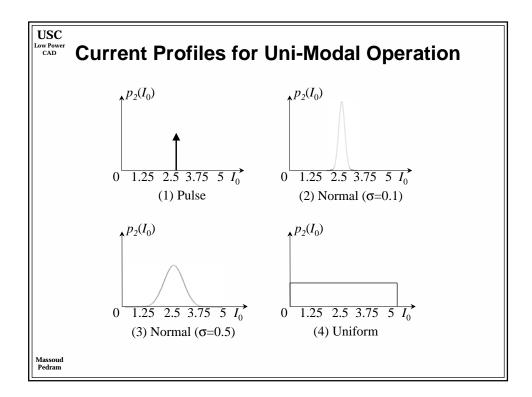


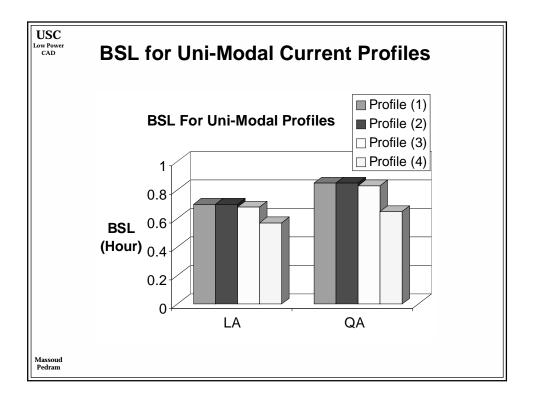


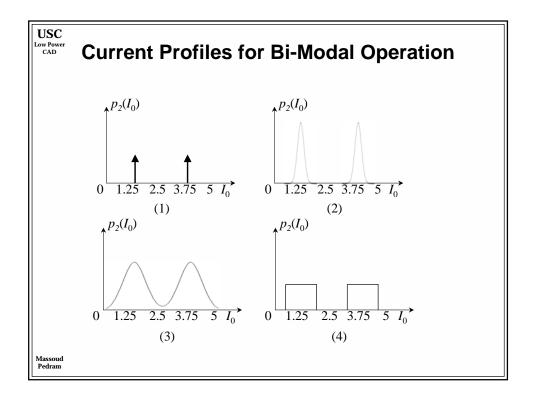


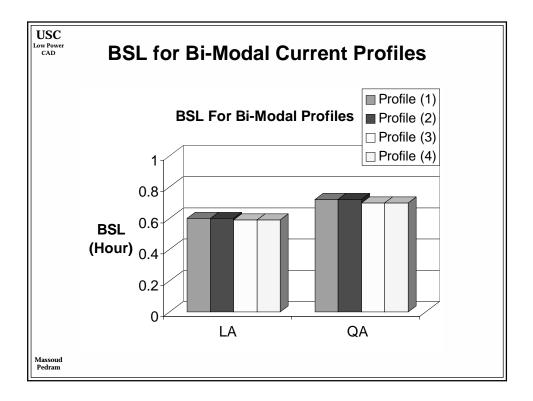


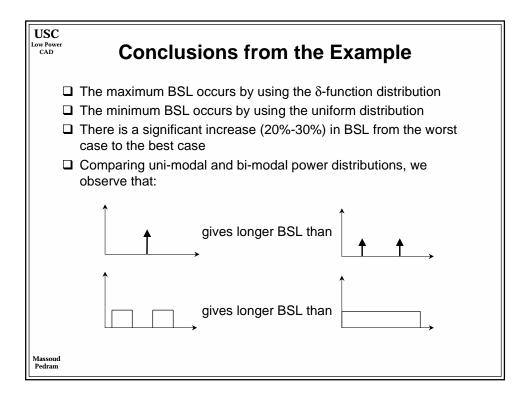


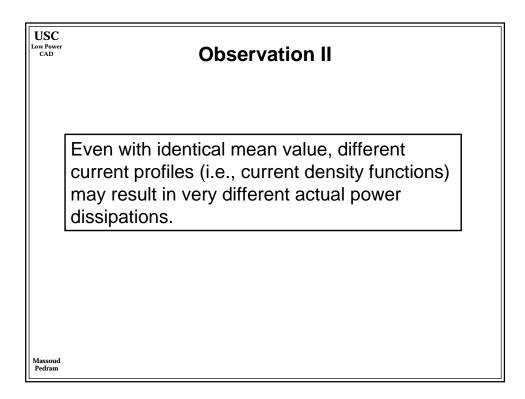


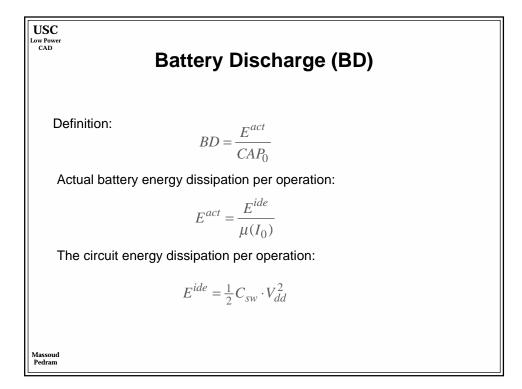


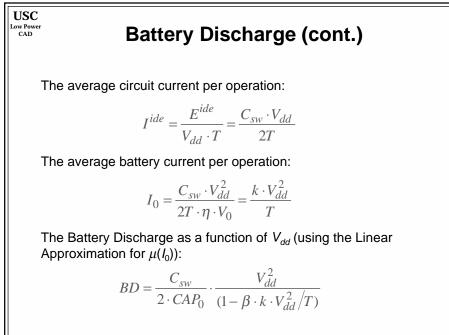




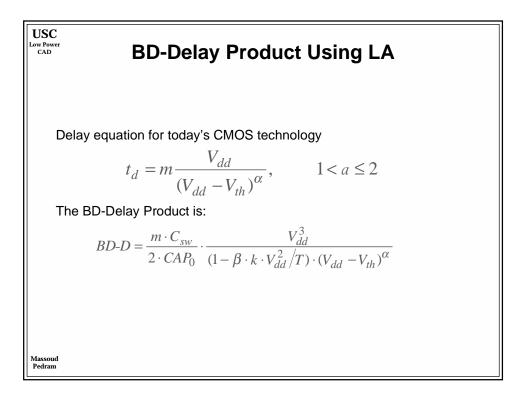




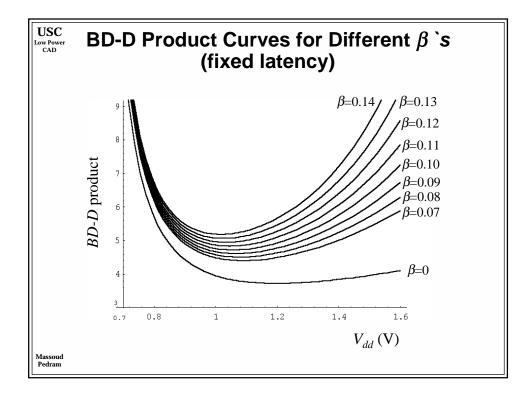


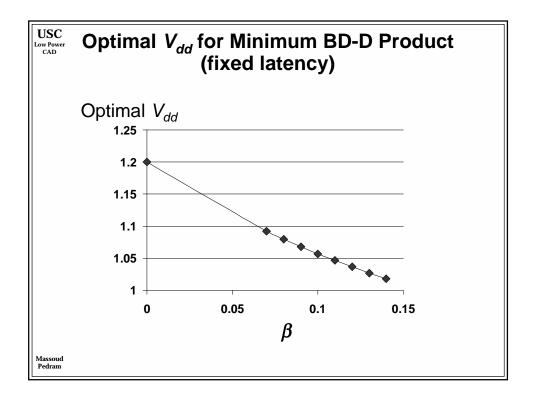


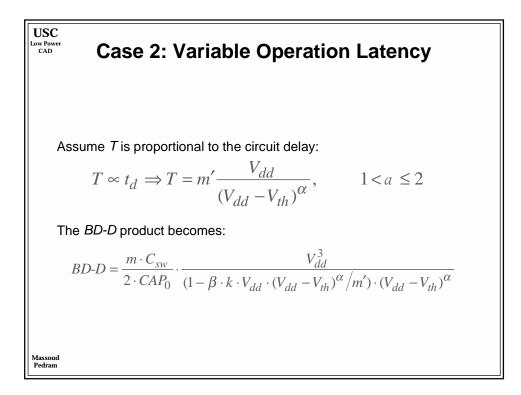
Massoud Pedram



Assume <i>T</i> is fixed for all $V_{dd}$ values. Consider a VLSI circuit which consumes 13.5W power at a supply voltage level of $V_{dd}$ =1.5V					
Г	Parameter	Value			
Г	$V_0$	4V			
Γ	η	0.9			
Γ	K/T	1.7			
Г	α	1.5			
	$V_{th}$	0.6V			
	$mC_{sw}/(2CAP_0)$	Normalized to 1			







USC Low Power CAD Analysis Setups					
	r a VLSI circuit which cons evel of <i>V<sub>dd</sub>=</i> 1.5V	sumes 13.5W power at a si	upply		
	Parameter	Value	1		
-	$V_0$	4V	1		
	η	0.9			
	K/m'	3.0			
	α	1.5			
	$V_{th}$	0.6V			
	$mC_{sw}/(2CAP_0)$	Normalized to 1	]		
Massoud Pedram					

